





MBR20150CT(LS)

SCHOTTKY BARRIER RECTIFIERS	REVERSE VOLTAGE – 150 Volts FORWARD CURRENT – 20 Amperes			
 FEATURES Metal of silicon rectifier, majority carrier conduction Guard ring for transient protection Low power loss, high efficiency Low leakage current High current capability, low V_F High surge capacity Plastic package has UL flammability classification 94V-0 IEC 61000-4-2, level 4 (ESD), >15KV (air) Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) MECHANICAL DATA Package: TO-220AB molded plastic Polarity: AS marked on the body Weight: 0.08 ounces, 2.24 grams Mounting position: Any Max. mounting torque = 0.5N.m (5.1Kgf.cm) 				
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTIC	S			

Ratings at 25°C ambient temperature unless otherwise specified.

CHARACTERISTICS			SYMBOL V _{RRM}	VALUE 150	UNIT
Maximum Recurrent Peak Reverse Voltage		V			
Maximum RMS Voltage			V _{RMS}	105	V
Maximum DC Blocking Voltage			V _{DC}	150	V
Maximum Average Forward Rectified Current (See Fig.1)		@T _c =120°C	I _(AV)	20	А
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load			I _{FSM}	180	A
Voltage Rate of Change (Rated V _R)			dv/dt	10000	V/us
Maximum Forward Voltage (Note 4)	I _F =10A I _F =10A I _F =20A I _F =20A	@ T _J =25°C @ T _J =125°C @ T _J =25°C @ T _J =125°C	VF	0.92 0.75 1.00 0.86	V
Maximum DC Reverse Current at Rated DC Blocking Voltage		@ T _J =25°C @ T _J =125°C	I _R	8 5	uA mA
Typical Thermal Resistance (Note 5	5)		R _{eJC}	2.0	°C/W
Typical Junction Capacitance per Element (Note 6)			CJ	250	pF
Operating Temperature Range			TJ	-55 to +175	°C
Storage Temperature Range			T _{STG}	-55 to +175	°C

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. 300us pulse width, 2% duty cycle.

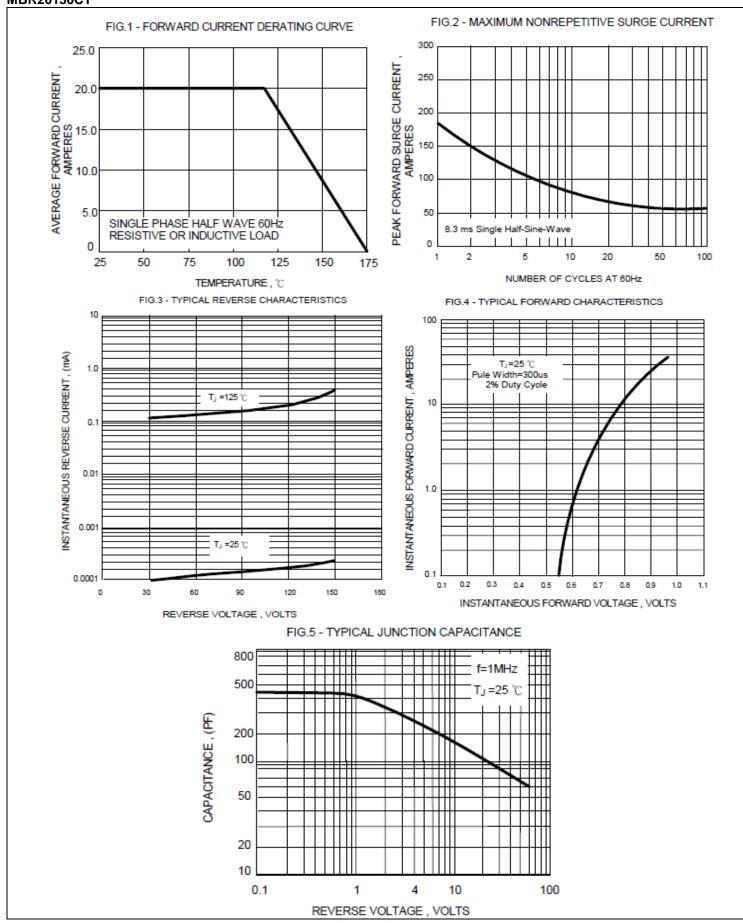
5. Thermal Resistance Junction to Case.

6. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.



RATING AND CHARACTERISTIC CURVES MBR20150CT

LITE-ON SEMICONDUCTOR

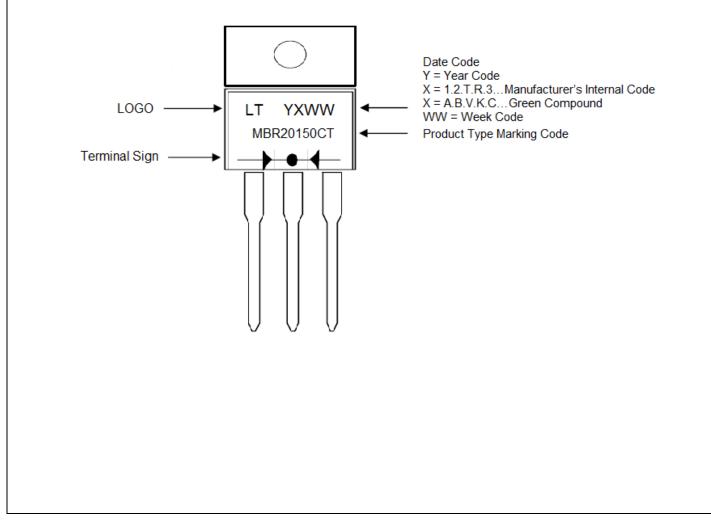




Ordering Information:

Part Number	Paakaga	Packing		
	Package	Qty.	Carrier	
MBR20150CT	TO-220AB	50 pcs	Tube	

Marking Information:





LITE-ON SEMICONDUCTOR

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